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### Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

### Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

#### Details

Product Status	Obsolete
Core Processor	PowerPC e300
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	400MHz
Co-Processors/DSP	Communications; QUICC Engine, Security; SEC
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (1)
SATA	-
USB	USB 1.x (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	-40°C ~ 105°C (TA)
Security Features	Cryptography, Random Number Generator
Package / Case	740-LBGA
Supplier Device Package	740-TBGA (37.5x37.5)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/kmc8358eczuagdga">https://www.e-xfl.com/product-detail/nxp-semiconductors/kmc8358eczuagdga</a>

- 10/100 Mbps Ethernet/IEEE Std. 802.3™ CDMA/CS interface through a media-independent interface (MII, RMII, RGMII)<sup>1</sup>
- 1000 Mbps Ethernet/IEEE 802.3 CDMA/CS interface through a media-independent interface (GMII, RGMII, TBI, RTBI) on UCC1 and UCC2
- 9.6-Kbyte jumbo frames
- ATM full-duplex SAR, up to 622 Mbps (OC-12/STM-4), AAL0, AAL1, and AAL5 in accordance ITU-T I.363.5
- ATM AAL2 CPS, SSSAR, and SSTED up to 155 Mbps (OC-3/STM-1) Mbps full duplex (with 4 CPS packets per cell) in accordance ITU-T I.366.1 and I.363.2
- ATM traffic shaping for CBR, VBR, UBR, and GFR traffic types compatible with ATM forum TM4.1 for up to 64-Kbyte simultaneous ATM channels
- ATM AAL1 structured and unstructured circuit emulation service (CES 2.0) in accordance with ITU-T I.163.1 and ATM Forum af-vtoa-00-0078.000
- IMA (Inverse Multiplexing over ATM) for up to 31 IMA links over 8 IMA groups in accordance with the ATM forum AF-PHY-0086.000 (Version 1.0) and AF-PHY-0086.001 (Version 1.1)
- ATM Transmission Convergence layer support in accordance with ITU-T I.432
- ATM OAM handling features compatible with ITU-T I.610
- PPP, Multi-Link (ML-PPP), Multi-Class (MC-PPP) and PPP mux in accordance with the following RFCs: 1661, 1662, 1990, 2686, and 3153
- IP support for IPv4 packets including TOS, TTL, and header checksum processing
- Ethernet over first mile IEEE 802.3ah
- Shim header
- Ethernet-to-Ethernet/AAL5/AAL2 inter-working
- L2 Ethernet switching using MAC address or IEEE Std. 802.1P/Q™ VLAN tags
- ATM (AAL2/AAL5) to Ethernet (IP) interworking in accordance with RFC2684 including bridging of ATM ports to Ethernet ports
- Extensive support for ATM statistics and Ethernet RMON/MIB statistics
- AAL2 protocol rate up to 4 CPS at OC-3/STM-1 rate
- Packet over Sonet (POS) up to 622-Mbps full-duplex 124 MultiPHY
- POS hardware; microcode must be loaded as an IRAM package
- Transparent up to 70-Mbps full-duplex
- HDLC up to 70-Mbps full-duplex
- HDLC BUS up to 10 Mbps
- Asynchronous HDLC
- UART
- BISYNC up to 2 Mbps
- User-programmable Virtual FIFO size
- QUICC multichannel controller (QMC) for 64 TDM channels
- One multichannel communication controller (MCC) only on the MPC8360E supporting the following:
  - 256 HDLC or transparent channels
  - 128 SS7 channels
  - Almost any combination of subgroups can be multiplexed to single or multiple TDM interfaces
- Two UTOPIA/POS interfaces on the MPC8360E supporting 124 MultiPHY each (optional 2\*128 MultiPHY with extended address) and one UTOPIA/POS interface on the MPC8358E supporting 31/124 MultiPHY
- Two serial peripheral interfaces (SPI); SPI2 is dedicated to Ethernet PHY management

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<sup>1</sup>.SMII or SGMII media-independent interface is not currently supported.

**Table 1. Absolute Maximum Ratings<sup>1</sup> (continued)**

Characteristic	Symbol	Max Value	Unit	Notes
Storage temperature range	T <sub>STG</sub>	–55 to 150	°C	—

**Notes:**

- Functional and tested operating conditions are given in [Table 2](#). Absolute maximum ratings are stress ratings only, and functional operation at the maximums is not guaranteed. Stresses beyond those listed may affect device reliability or cause permanent damage to the device.
- Caution:** MV<sub>IN</sub> must not exceed GV<sub>DD</sub> by more than 0.3 V. This limit may be exceeded for a maximum of 100 ms during power-on reset and power-down sequences.
- Caution:** OV<sub>IN</sub> must not exceed OV<sub>DD</sub> by more than 0.3 V. This limit may be exceeded for a maximum of 100 ms during power-on reset and power-down sequences.
- Caution:** LV<sub>IN</sub> must not exceed LV<sub>DD</sub> by more than 0.3 V. This limit may be exceeded for a maximum of 100 ms during power-on reset and power-down sequences.
- (M,L,O)V<sub>IN</sub> and MV<sub>REF</sub> may overshoot/undershoot to a voltage and for a maximum duration as shown in [Figure 3](#).
- OV<sub>IN</sub> on the PCI interface may overshoot/undershoot according to the PCI Electrical Specification for 3.3-V operation, as shown in [Figure 4](#).

## 2.1.2 Power Supply Voltage Specification

This table provides the recommended operating conditions for the device. Note that the values in this table are the recommended and tested operating conditions. Proper device operation outside of these conditions is not guaranteed.

**Table 2. Recommended Operating Conditions**

Characteristic	Symbol	Recommended Value	Unit	Notes
Core and PLL supply voltage for  MPC8358 Device Part Number with Processor Frequency label of AD=266MHz and AG=400MHz & QUICC Engine Frequency label of E=300MHz & G=400MHz  MPC8360 Device Part Number with Processor Frequency label of AG=400MHz and AJ=533MHz & QUICC Engine Frequency label of G=400MHz	V <sub>DD</sub> & AV <sub>DD</sub>	1.2 V ± 60 mV	V	1, 3
Core and PLL supply voltage for  MPC8360 Device Part Number with Processor Frequency label of AL=667MHz and QUICC Engine Frequency label of H=500MHz	V <sub>DD</sub> & AV <sub>DD</sub>	1.3 V ± 50 mV	V	1, 3
DDR and DDR2 DRAM I/O supply voltage  DDR DDR2	GV <sub>DD</sub>	2.5 V ± 125 mV 1.8 V ± 90 mV	V	—
Three-speed Ethernet I/O supply voltage	LV <sub>DD0</sub>	3.3 V ± 330 mV 2.5 V ± 125 mV	V	—
Three-speed Ethernet I/O supply voltage	LV <sub>DD1</sub>	3.3 V ± 330 mV 2.5 V ± 125 mV	V	—
Three-speed Ethernet I/O supply voltage	LV <sub>DD2</sub>	3.3 V ± 330 mV 2.5 V ± 125 mV	V	—

This figure shows the undershoot and overshoot voltage of the PCI interface of the device for the 3.3-V signals, respectively.

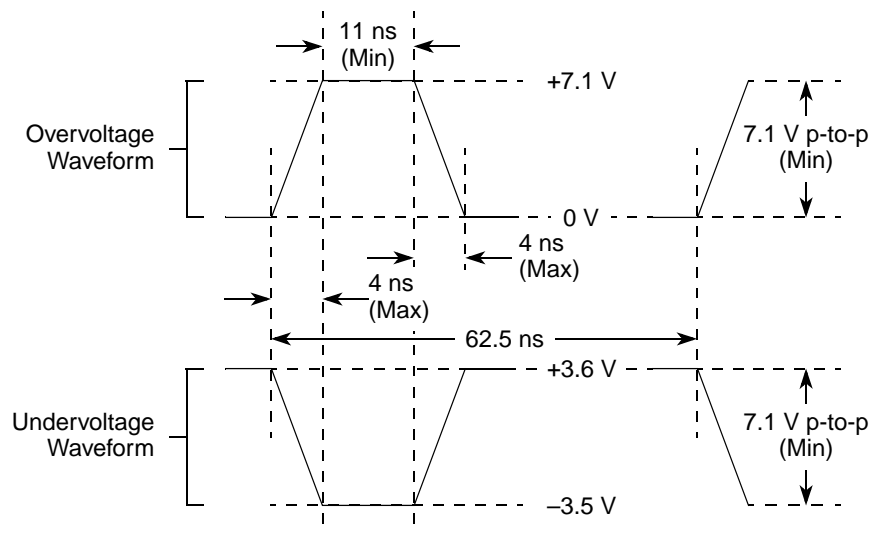


Figure 4. Maximum AC Waveforms on PCI interface for 3.3-V Signaling

## 2.1.3 Output Driver Characteristics

This table provides information on the characteristics of the output driver strengths. The values are preliminary estimates.

Table 3. Output Drive Capability

Driver Type	Output Impedance ( $\Omega$ )	Supply Voltage
Local bus interface utilities signals	42	$OV_{DD} = 3.3\text{ V}$
PCI signals	25	
PCI output clocks (including PCI_SYNC_OUT)	42	
DDR signal	20 36 (half-strength mode) <sup>1</sup>	$GV_{DD} = 2.5\text{ V}$
DDR2 signal	18 36 (half-strength mode) <sup>1</sup>	$GV_{DD} = 1.8\text{ V}$
10/100/1000 Ethernet signals	42	$LV_{DD} = 2.5/3.3\text{ V}$
DUART, system control, I <sup>2</sup> C, SPI, JTAG	42	$OV_{DD} = 3.3\text{ V}$
GPIO signals	42	$OV_{DD} = 3.3\text{ V}$ $LV_{DD} = 2.5/3.3\text{ V}$

**Note:**

1. DDR output impedance values for half strength mode are verified by design and not tested.

## 2.2 Power Sequencing

This section details the power sequencing considerations for the MPC8360E/58E.

## 2.2.1 Power-Up Sequencing

MPC8360E/58E does not require the core supply voltage ( $V_{DD}$  and  $AV_{DD}$ ) and I/O supply voltages ( $GV_{DD}$ ,  $LV_{DD}$ , and  $OV_{DD}$ ) to be applied in any particular order. During the power ramp up, before the power supplies are stable and if the I/O voltages are supplied before the core voltage, there may be a period of time that all input and output pins are actively be driven and cause contention and excessive current from 3A to 5A. In order to avoid actively driving the I/O pins and to eliminate excessive current draw, apply the core voltage ( $V_{DD}$ ) before the I/O voltage ( $GV_{DD}$ ,  $LV_{DD}$ , and  $OV_{DD}$ ) and assert **PORESET** before the power supplies fully ramp up. In the case where the core voltage is applied first, the core voltage supply must rise to 90% of its nominal value before the I/O supplies reach 0.7 V, see this figure.

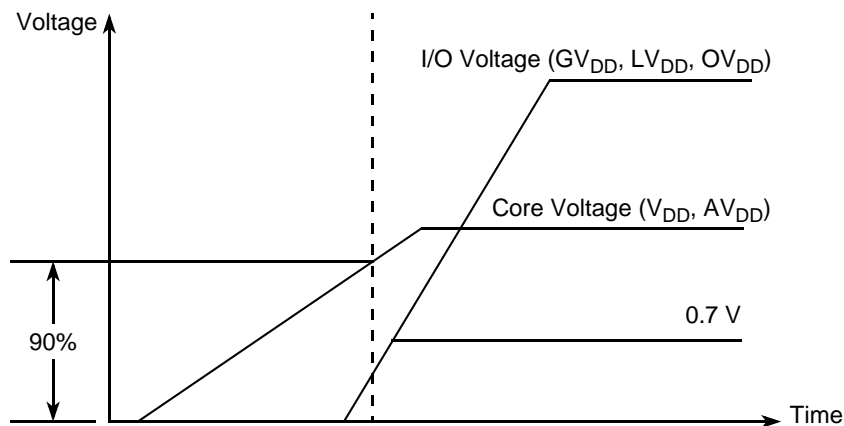


Figure 5. Power Sequencing Example

I/O voltage supplies ( $GV_{DD}$ ,  $LV_{DD}$ , and  $OV_{DD}$ ) do not have any ordering requirements with respect to one another.

## 2.2.2 Power-Down Sequencing

The MPC8360E/58E does not require the core supply voltage and I/O supply voltages to be powered down in any particular order.

# 3 Power Characteristics

The estimated typical power dissipation values are shown in these tables.

Table 4. MPC8360E TBGA Core Power Dissipation<sup>1</sup>

Core Frequency (MHz)	CSB Frequency (MHz)	QUICC Engine Frequency (MHz)	Typical	Maximum	Unit	Notes
266	266	500	5.0	5.6	W	2, 3, 5
400	266	400	4.5	5.0	W	2, 3, 4
533	266	400	4.8	5.3	W	2, 3, 4
667	333	400	5.8	6.3	W	3, 6, 7, 8
500	333	500	5.9	6.4	W	3, 6, 7, 8

**Table 16. DDR SDRAM DC Electrical Characteristics for  $GV_{DD}(typ) = 2.5\text{ V}$  (continued)**

Parameter/Condition	Symbol	Min	Max	Unit	Notes
Input high voltage	$V_{IH}$	$MV_{REF} + 0.18$	$GV_{DD} + 0.3$	V	—
Input low voltage	$V_{IL}$	-0.3	$MV_{REF} - 0.18$	V	—
Output leakage current	$I_{OZ}$	—	$\pm 10$	$\mu\text{A}$	4
Output high current ( $V_{OUT} = 1.95\text{ V}$ )	$I_{OH}$	-15.2	—	mA	—
Output low current ( $V_{OUT} = 0.35\text{ V}$ )	$I_{OL}$	15.2	—	mA	—
$MV_{REF}$ input leakage current	$I_{VREF}$	—	$\pm 10$	$\mu\text{A}$	—
Input current ( $0\text{ V} \leq V_{IN} \leq OV_{DD}$ )	$I_{IN}$	—	$\pm 10$	$\mu\text{A}$	—

**Notes:**

1.  $GV_{DD}$  is expected to be within 50 mV of the DRAM  $GV_{DD}$  at all times.
2.  $MV_{REF}$  is expected to be equal to  $0.5 \times GV_{DD}$ , and to track  $GV_{DD}$  DC variations as measured at the receiver. Peak-to-peak noise on  $MV_{REF}$  may not exceed  $\pm 2\%$  of the DC value.
3.  $V_{TT}$  is not applied directly to the device. It is the supply to which far end signal termination is made and is expected to be equal to  $MV_{REF}$ . This rail should track variations in the DC level of  $MV_{REF}$ .
4. Output leakage is measured with all outputs disabled,  $0\text{ V} \leq V_{OUT} \leq GV_{DD}$ .

This table provides the DDR capacitance when  $GV_{DD}(typ) = 2.5\text{ V}$ .

**Table 17. DDR SDRAM Capacitance for  $GV_{DD}(typ) = 2.5\text{ V}$** 

Parameter/Condition	Symbol	Min	Max	Unit	Notes
Input/output capacitance: DQ, DQS	$C_{IO}$	6	8	pF	1
Delta input/output capacitance: DQ, DQS	$C_{DIO}$	—	0.5	pF	1

**Note:**

1. This parameter is sampled.  $GV_{DD} = 2.5\text{ V} \pm 0.125\text{ V}$ ,  $f = 1\text{ MHz}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{OUT} = GV_{DD}/2$ ,  $V_{OUT}$  (peak-to-peak) = 0.2 V.

## 6.2 DDR and DDR2 SDRAM AC Electrical Characteristics

This section provides the AC electrical characteristics for the DDR and DDR2 SDRAM interface.

### 6.2.1 DDR and DDR2 SDRAM Input AC Timing Specifications

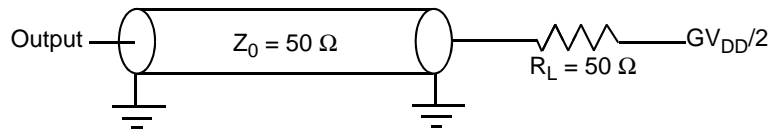
This table provides the input AC timing specifications for the DDR2 SDRAM interface when  $GV_{DD}(typ) = 1.8\text{ V}$ .

**Table 18. DDR2 SDRAM Input AC Timing Specifications for  $GV_{DD}(typ) = 1.8\text{ V}$** 

At recommended operating conditions with  $GV_{DD}$  of  $1.8\text{ V} \pm 5\%$ .

Parameter	Symbol	Min	Max	Unit	Notes
AC input low voltage	$V_{IL}$	—	$MV_{REF} - 0.25$	V	—
AC input high voltage	$V_{IH}$	$MV_{REF} + 0.25$	—	V	—

This figure provides the AC test load for the DDR bus.



**Figure 8. DDR AC Test Load**

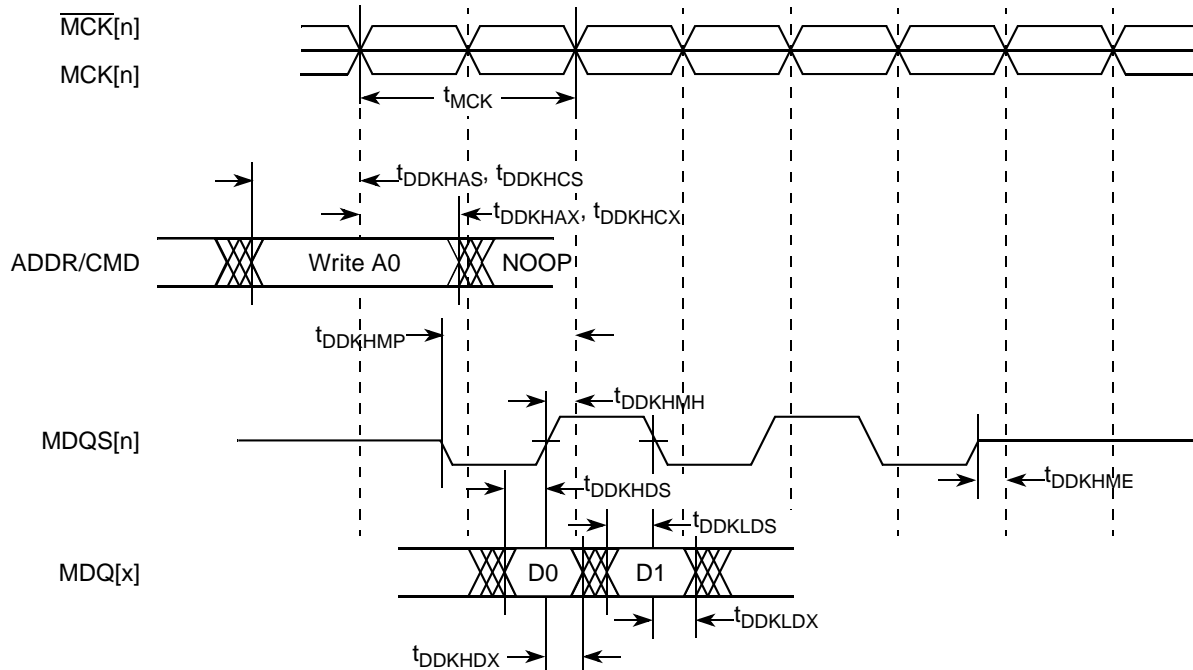
**Table 22. DDR and DDR2 SDRAM Measurement Conditions**

Symbol	DDR	DDR2	Unit	Notes
$V_{TH}$	$MV_{REF} \pm 0.31\text{ V}$	$MV_{REF} \pm 0.25\text{ V}$	V	1
$V_{OUT}$	$0.5 \times GV_{DD}$	$0.5 \times GV_{DD}$	V	2

**Notes:**

1. Data input threshold measurement point.
2. Data output measurement point.

This figure shows the DDR SDRAM output timing diagram for source synchronous mode.



**Figure 9. DDR SDRAM Output Timing Diagram for Source Synchronous Mode**

## 8.2.1.2 GMII Receive AC Timing Specifications

This table provides the GMII receive AC timing specifications.

**Table 28. GMII Receive AC Timing Specifications**

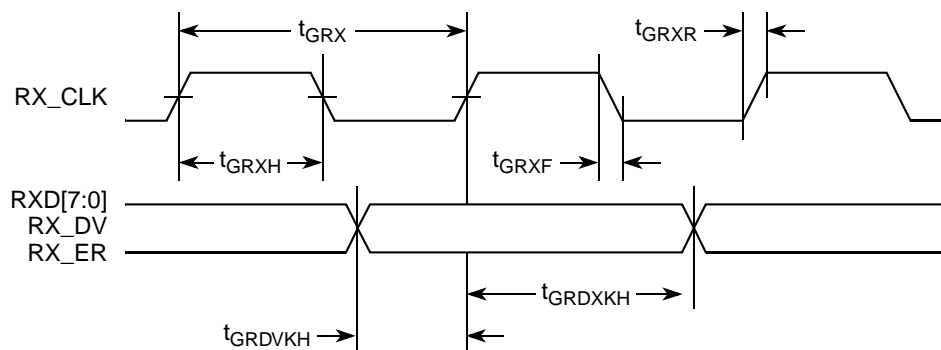
At recommended operating conditions with  $V_{DD}/OV_{DD}$  of  $3.3\text{ V} \pm 10\%$ .

Parameter/Condition	Symbol <sup>1</sup>	Min	Typ	Max	Unit	Notes
RX_CLK clock period	$t_{GRX}$	—	8.0	—	ns	—
RX_CLK duty cycle	$t_{GRXH}/t_{GRX}$	40	—	60	%	—
RXD[7:0], RX_DV, RX_ER setup time to RX_CLK	$t_{GRDVKH}$	2.0	—	—	ns	—
RXD[7:0], RX_DV, RX_ER hold time to RX_CLK	$t_{GRDXKH}$	0.2	—	—	ns	2
RX_CLK clock rise time, (20% to 80%)	$t_{GRXR}$	—	—	1.0	ns	—
RX_CLK clock fall time, (80% to 20%)	$t_{GRXF}$	—	—	1.0	ns	—

**Notes:**

- The symbols used for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{GRDVKH}$  symbolizes GMII receive timing (GR) with respect to the time data input signals (D) reaching the valid state (V) relative to the  $t_{RX}$  clock reference (K) going to the high state (H) or setup time. Also,  $t_{GRDXKL}$  symbolizes GMII receive timing (GR) with respect to the time data input signals (D) went invalid (X) relative to the  $t_{GRX}$  clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of  $t_{GRX}$  represents the GMII (G) receive (RX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
- In rev. 2.0 silicon, due to errata,  $t_{GRDXKH}$  minimum is 0.5 which is not compliant with the standard. Refer to Errata *QE\_ENET18* in *Chip Errata for the MPC8360E, Rev. 1*.

This figure shows the GMII receive AC timing diagram.



**Figure 11. GMII Receive AC Timing Diagram**



## 8.2.2 MII AC Timing Specifications

This section describes the MII transmit and receive AC timing specifications.

### 8.2.2.1 MII Transmit AC Timing Specifications

This table provides the MII transmit AC timing specifications.

**Table 29. MII Transmit AC Timing Specifications**

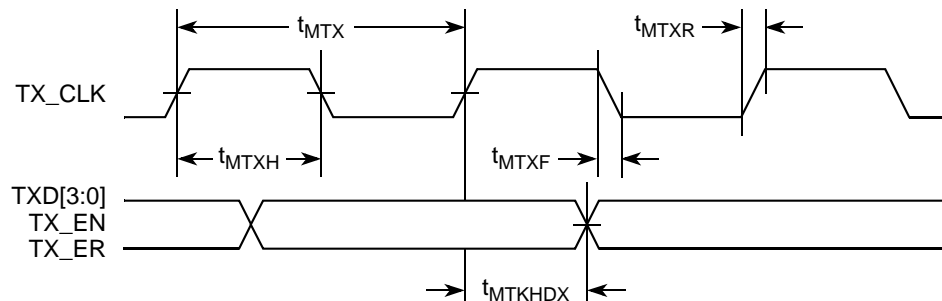
At recommended operating conditions with  $V_{DD}/OV_{DD}$  of  $3.3\text{ V} \pm 10\%$ .

Parameter/Condition	Symbol <sup>1</sup>	Min	Typ	Max	Unit
TX_CLK clock period 10 Mbps	$t_{MTX}$	—	400	—	ns
TX_CLK clock period 100 Mbps	$t_{MTX}$	—	40	—	ns
TX_CLK duty cycle	$t_{MTXH}/t_{MTX}$	35	—	65	%
TX_CLK to MII data TXD[3:0], TX_ER, TX_EN delay	$t_{MTKHDX}$ $t_{MTKHDV}$	1 —	5	— 15	ns
TX_CLK data clock rise time, (20% to 80%)	$t_{MTXR}$	1.0	—	4.0	ns
TX_CLK data clock fall time, (80% to 20%)	$t_{MTXF}$	1.0	—	4.0	ns

**Note:**

- The symbols used for timing specifications follow the pattern of  $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$  for inputs and  $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$  for outputs. For example,  $t_{MTKHDX}$  symbolizes MII transmit timing (MT) for the time  $t_{MTX}$  clock reference (K) going high (H) until data outputs (D) are invalid (X). Note that, in general, the clock reference symbol representation is based on two to three letters representing the clock of a particular functional. For example, the subscript of  $t_{MTX}$  represents the MII(M) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

This figure shows the MII transmit AC timing diagram.



**Figure 12. MII Transmit AC Timing Diagram**

### 8.3.3 IEEE 1588 Timer AC Specifications

This table provides the IEEE 1588 timer AC specifications.

**Table 38. IEEE 1588 Timer AC Specifications**

Parameter	Symbol	Min	Max	Unit	Notes
Timer clock frequency	$t_{TMRCK}$	0	70	MHz	1
Input setup to timer clock	$t_{TMRCKS}$	—	—	—	2, 3
Input hold from timer clock	$t_{TMRCKH}$	—	—	—	2, 3
Output clock to output valid	$t_{GCLKNV}$	0	6	ns	—
Timer alarm to output valid	$t_{TMRAL}$	—	—	—	2

**Notes:**

1. The timer can operate on `rtc_clock` or `tmr_clock`. These clocks get muxed and any one of them can be selected. The minimum and maximum requirement for both `rtc_clock` and `tmr_clock` are the same.
2. These are asynchronous signals.
3. Inputs need to be stable at least one TMR clock.

## 9 Local Bus

This section describes the DC and AC electrical specifications for the local bus interface of the MPC8360E/58E.

### 9.1 Local Bus DC Electrical Characteristics

This table provides the DC electrical characteristics for the local bus interface.

**Table 39. Local Bus DC Electrical Characteristics**

Parameter	Symbol	Min	Max	Unit
High-level input voltage	$V_{IH}$	2	$OV_{DD} + 0.3$	V
Low-level input voltage	$V_{IL}$	-0.3	0.8	V
High-level output voltage, $I_{OH} = -100 \mu A$	$V_{OH}$	$OV_{DD} - 0.4$	—	V
Low-level output voltage, $I_{OL} = 100 \mu A$	$V_{OL}$	—	0.2	V
Input current	$I_{IN}$	—	$\pm 10$	$\mu A$

### 9.2 Local Bus AC Electrical Specifications

This table describes the general timing parameters of the local bus interface of the device.

**Table 40. Local Bus General Timing Parameters—DLL Enabled**

Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
Local bus cycle time	$t_{LBK}$	7.5	—	ns	2
Input setup to local bus clock (except LUPWAIT)	$t_{LBIVKH1}$	1.7	—	ns	3, 4
LUPWAIT input setup to local bus clock	$t_{LBIVKH2}$	1.9	—	ns	3, 4
Input hold from local bus clock (except LUPWAIT)	$t_{LBIXKH1}$	1.0	—	ns	3, 4

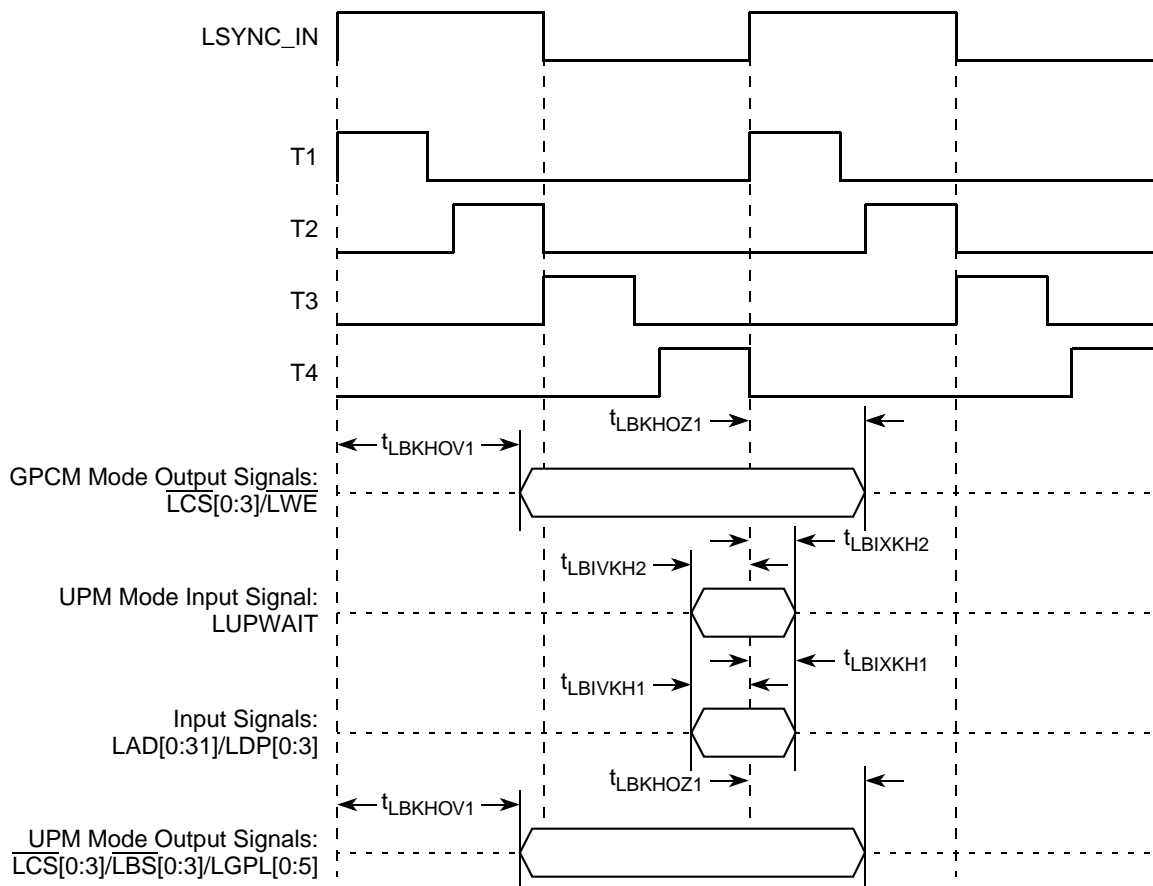


Figure 28. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 4 (DLL Enabled)

## 10 JTAG

This section describes the DC and AC electrical specifications for the IEEE 1149.1 (JTAG) interface of the MPC8360E/58E.

### 10.1 JTAG DC Electrical Characteristics

This table provides the DC electrical characteristics for the IEEE 1149.1 (JTAG) interface of the device.

Table 42. JTAG interface DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	$V_{OH}$	$I_{OH} = -6.0 \text{ mA}$	2.4	—	V
Output low voltage	$V_{OL}$	$I_{OL} = 6.0 \text{ mA}$	—	0.5	V
Output low voltage	$V_{OL}$	$I_{OL} = 3.2 \text{ mA}$	—	0.4	V
Input high voltage	$V_{IH}$	—	2.5	$OV_{DD} + 0.3$	V
Input low voltage	$V_{IL}$	—	-0.3	0.8	V
Input current	$I_{IN}$	$0 \text{ V} \leq V_{IN} \leq OV_{DD}$	—	$\pm 10$	$\mu\text{A}$

## 10.2 JTAG AC Electrical Characteristics

This section describes the AC electrical specifications for the IEEE 1149.1 (JTAG) interface of the device.

This table provides the JTAG AC timing specifications as defined in Figure 30 through Figure 33.

**Table 43. JTAG AC Timing Specifications (Independent of CLKIN)<sup>1</sup>**

At recommended operating conditions (see Table 2).

Parameter	Symbol <sup>2</sup>	Min	Max	Unit	Notes
JTAG external clock frequency of operation	$f_{JTG}$	0	33.3	MHz	—
JTAG external clock cycle time	$t_{JTG}$	30	—	ns	—
JTAG external clock duty cycle	$t_{JTKHKL}/t_{JTG}$	45	55	%	—
JTAG external clock rise and fall times	$t_{JTGR}$ & $t_{JTGF}$	0	2	ns	—
$\overline{TRST}$ assert time	$t_{TRST}$	25	—	ns	3
Input setup times:				ns	4
Boundary-scan data TMS, TDI	$t_{JTDVKH}$ $t_{JTIVKH}$	4 4	— —		
Input hold times:				ns	4
Boundary-scan data TMS, TDI	$t_{JTDXKH}$ $t_{JTIXKH}$	10 10	— —		
Valid times:				ns	5
Boundary-scan data TDO	$t_{JTKLDV}$ $t_{JTKLOV}$	2 2	11 11		
Output hold times:				ns	5
Boundary-scan data TDO	$t_{JTKLDX}$ $t_{JTKLOX}$	2 2	— —		
JTAG external clock to output high impedance:				ns	5, 6
Boundary-scan data TDO	$t_{JTKLDZ}$ $t_{JTKLOZ}$	2 2	19 9		

### Notes:

- All outputs are measured from the midpoint voltage of the falling/rising edge of  $t_{TCLK}$  to the midpoint of the signal in question. The output timings are measured at the pins. All output timings assume a purely resistive 50- $\Omega$  load (see Figure 22). Time-of-flight delays must be added for trace lengths, vias, and connectors in the system.
- The symbols used for timing specifications herein follow the pattern of  $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)}$  (reference)(state) for inputs and  $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{JTDVKH}$  symbolizes JTAG device timing (JT) with respect to the time data input signals (D) reaching the valid state (V) relative to the  $t_{JTG}$  clock reference (K) going to the high (H) state or setup time. Also,  $t_{JTDXKH}$  symbolizes JTAG timing (JT) with respect to the time data input signals (D) went invalid (X) relative to the  $t_{JTG}$  clock reference (K) going to the high (H) state. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
- $\overline{TRST}$  is an asynchronous level sensitive signal. The setup time is for test purposes only.
- Non-JTAG signal input timing with respect to  $t_{TCLK}$ .
- Non-JTAG signal output timing with respect to  $t_{TCLK}$ .
- Guaranteed by design and characterization.

Table 47. PCI AC Timing Specifications at 66 MHz (continued)

Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
Clock to output high impedance	$t_{PCKHOZ}$	—	14	ns	2, 3
Input setup to clock	$t_{PCIVKH}$	3.0	—	ns	2, 4
Input hold from clock	$t_{PCIXKH}$	0.3	—	ns	2, 4, 6

**Notes:**

- The symbols used for timing specifications follow the pattern of  $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)(reference)(state)}$  for inputs and  $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{PCIVKH}$  symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI\_SYNC\_IN clock,  $t_{SYS}$ , reference (K) going to the high (H) state or setup time. Also,  $t_{PCRHFV}$  symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
- See the timing measurement conditions in the *PCI 2.2 Local Bus Specifications*.
- For purposes of active/float timing measurements, the Hi-Z or off-state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- Input timings are measured at the pin.
- In rev. 2.0 silicon, due to errata,  $t_{PCIHOV}$  maximum is 6.6 ns. Refer to Errata PCI21 in *Chip Errata for the MPC8360E, Rev. 1*.
- In rev. 2.0 silicon, due to errata,  $t_{PCIXKH}$  minimum is 1 ns. Refer to Errata PCI17 in *Chip Errata for the MPC8360E, Rev. 1*.

Table 48. PCI AC Timing Specifications at 33 MHz

Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
Clock to output valid	$t_{PCKHOV}$	—	11	ns	2
Output hold from clock	$t_{PCKHOX}$	2	—	ns	2
Clock to output high impedance	$t_{PCKHOZ}$	—	14	ns	2, 3
Input setup to clock	$t_{PCIVKH}$	7.0	—	ns	2, 2
Input hold from clock	$t_{PCIXKH}$	0.3	—	ns	2, 4, 5

**Notes:**

- The symbols used for timing specifications herein follow the pattern of  $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)(reference)(state)}$  for inputs and  $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{PCIVKH}$  symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI\_SYNC\_IN clock,  $t_{SYS}$ , reference (K) going to the high (H) state or setup time. Also,  $t_{PCRHFV}$  symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
- See the timing measurement conditions in the *PCI 2.2 Local Bus Specifications*.
- For purposes of active/float timing measurements, the Hi-Z or off-state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- Input timings are measured at the pin.
- In rev. 2.0 silicon, due to errata,  $t_{PCIXKH}$  minimum is 1 ns. Refer to Errata PCI17 in *Chip Errata for the MPC8360E, Rev. 1*.

This figure provides the AC test load for PCI.

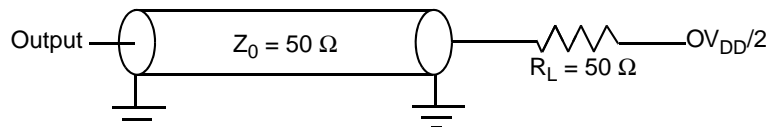


Figure 36. PCI AC Test Load

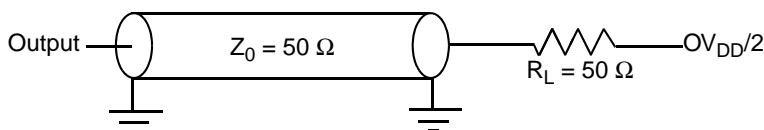
**Table 60. UTOPIA AC Timing Specifications<sup>1</sup> (continued)**

Characteristic	Symbol <sup>2</sup>	Min	Max	Unit	Notes
UTOPIA inputs—Internal clock input hold time	$t_{UIIXKH}$	2.4	—	ns	—
UTOPIA inputs—External clock input hold time	$t_{UEIXKH}$	1	—	ns	3

**Notes:**

1. Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.
2. The symbols used for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{UIKHGX}$  symbolizes the UTOPIA outputs internal timing (UI) for the time  $t_{UTOPIA}$  memory clock reference (K) goes from the high state (H) until outputs (O) are invalid (X).
3. In rev. 2.0 silicon, due to errata,  $t_{UEIVKH}$  minimum is 4.3 ns and  $t_{UEIXKH}$  minimum is 1.4 ns under specific conditions. Refer to Errata QE\_UPC3 in *Chip Errata for the MPC8360E, Rev. 1*.

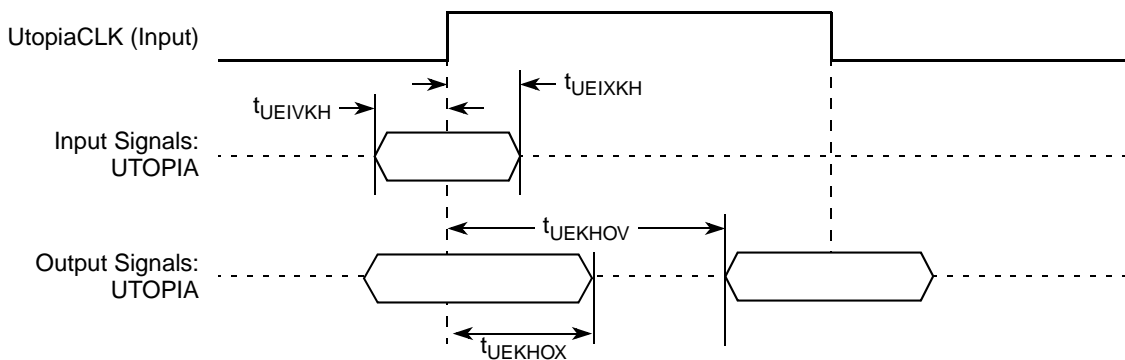
This figure provides the AC test load for the UTOPIA.



**Figure 46. UTOPIA AC Test Load**

These figures represent the AC timing from Table 56. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.

This figure shows the UTOPIA timing with external clock.



**Figure 47. UTOPIA AC Timing (External Clock) Diagram**

Table 66. MPC8360E TBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
PCI_DEVSEL/CE_PF[16]	E26	I/O	OV <sub>DD</sub>	5
PCI_IDSEL/CE_PF[17]	F22	I/O	OV <sub>DD</sub>	—
PCI_SERR/CE_PF[18]	B29	I/O	OV <sub>DD</sub>	5
PCI_PERR/CE_PF[19]	A29	I/O	OV <sub>DD</sub>	5
PCI_REQ[0]/CE_PF[20]	F19	I/O	LV <sub>DD2</sub>	—
PCI_REQ[1]/CPCI_HS_ES/ CE_PF[21]	A21	I/O	LV <sub>DD2</sub>	—
PCI_REQ[2]/CE_PF[22]	C21	I/O	LV <sub>DD2</sub>	—
PCI_GNT[0]/CE_PF[23]	E20	I/O	LV <sub>DD2</sub>	—
PCI_GNT[1]/CPCI1_HS_LED/ CE_PF[24]	B20	I/O	LV <sub>DD2</sub>	—
PCI_GNT[2]/CPCI1_HS_ENUM/ CE_PF[25]	C20	I/O	LV <sub>DD2</sub>	—
PCI_MODE	D36	I	OV <sub>DD</sub>	—
M66EN/CE_PF[4]	B37	I/O	OV <sub>DD</sub>	—
<b>Local Bus Controller Interface</b>				
LAD[0:31]	N32, N33, N35, N36, P37, P32, P34, R36, R35, R34, R33, T37, T35, T34, T33, U37, T32, U36, U34, V36, V35, W37, W35, V33, V32, W34, Y36, W32, AA37, Y33, AA35, AA34	I/O	OV <sub>DD</sub>	—
LDP[0]/CKSTOP_OUT	AB37	I/O	OV <sub>DD</sub>	—
LDP[1]/CKSTOP_IN	AB36	I/O	OV <sub>DD</sub>	—
LDP[2]/LCS[6]	AB35	I/O	OV <sub>DD</sub>	—
LDP[3]/LCS[7]	AA33	I/O	OV <sub>DD</sub>	—
LA[27:31]	AC37, AA32, AC36, AC34, AD36	O	OV <sub>DD</sub>	—
LCS[0:5]	AD33, AG37, AF34, AE33, AD32, AH37	O	OV <sub>DD</sub>	—
LWE[0:3]/LSDDQM[0:3]/LBS[0:3]	AG35, AG34, AH36, AE32	O	OV <sub>DD</sub>	—
LBCTL	AD35	O	OV <sub>DD</sub>	—
LALE	M37	O	OV <sub>DD</sub>	—
LGPL0/LSDA10/cfg_reset_source0	AB32	I/O	OV <sub>DD</sub>	—
LGPL1/LSDWE/cfg_reset_source1	AE37	I/O	OV <sub>DD</sub>	—
LGPL2/LSDRAS/LOE	AC33	O	OV <sub>DD</sub>	—
LGPL3/LSDCAS/cfg_reset_source2	AD34	I/O	OV <sub>DD</sub>	—
LGPL4/LGTA/LUPWAIT/LPBSE	AE35	I/O	OV <sub>DD</sub>	—
LGPL5/cfg_clkin_div	AF36	I/O	OV <sub>DD</sub>	—
LCKE	G36	O	OV <sub>DD</sub>	—
LCLK[0]	J33	O	OV <sub>DD</sub>	—
LCLK[1]/LCS[6]	J34	O	OV <sub>DD</sub>	—

Table 67. MPC8358E TBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
PORESET	L37	I	OV <sub>DD</sub>	—
HRESET	L36	I/O	OV <sub>DD</sub>	1
SRESET	M33	I/O	OV <sub>DD</sub>	2
Thermal Management				
THERM0	AP19	I	GV <sub>DD</sub>	—
THERM1	AT31	I	GV <sub>DD</sub>	—
Power and Ground Signals				
AV <sub>DD</sub> 1	K35	Power for LBIU DLL (1.2 V)	AV <sub>DD</sub> 1	—
AV <sub>DD</sub> 2	K36	Power for CE PLL (1.2 V)	AV <sub>DD</sub> 2	—
AV <sub>DD</sub> 5	AM29	Power for e300 PLL (1.2 V)	AV <sub>DD</sub> 5	—
AV <sub>DD</sub> 6	K37	Power for system PLL (1.2 V)	AV <sub>DD</sub> 6	—
GND	A2, A8, A13, A19, A22, A25, A31, A33, A36, B7, B12, B24, B27, B30, C4, C6, C9, C15, C26, C32, D3, D8, D11, D14, D17, D19, D23, D27, E7, E13, E25, E30, E36, F4, F37, G34, H1, H5, H32, H33, J4, J32, J37, K1, L3, L5, L33, L34, M1, M34, M35, N37, P2, P5, P35, P36, R4, T3, U1, U5, U35, V37, W1, W4, W33, W36, Y34, AA3, AA5, AC3, AC32, AC35, AD1, AD37, AE4, AE34, AE36, AF33, AG4, AG6, AG32, AH35, AJ1, AJ4, AJ32, AJ35, AJ37, AK36, AL3, AL34, AM4, AN6, AN23, AN30, AP8, AP12, AP14, AP16, AP17, AP20, AP25, AR6, AR8, AR9, AR19, AR24, AR31, AR35, AR37, AT4, AT10, AT19, AT20, AT25, AU14, AU22, AU28, AU35	—	—	—
GV <sub>DD</sub>	AD4, AE3, AF1, AF5, AF35, AF37, AG2, AG36, AH33, AH34, AK5, AM1, AM35, AM37, AN2, AN10, AN11, AN12, AN14, AN32, AN36, AP5, AP23, AP28, AR1, AR7, AR10, AR12, AR21, AR25, AR27, AR33, AT15, AT22, AT28, AT33, AU2, AU5, AU16, AU31, AU36	Power for DDR DRAM I/O voltage (2.5 or 1.8 V)	GV <sub>DD</sub>	—
LV <sub>DD</sub> 0	D5, D6	Power for UCC1 Ethernet interface (2.5 V, 3.3 V)	LV <sub>DD</sub> 0	—



Table 67. MPC8358E TBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
LV <sub>DD</sub> 1	C17, D16	Power for UCC2 Ethernet interface option 1 (2.5 V, 3.3 V)	LV <sub>DD</sub> 1	9
LV <sub>DD</sub> 2	B18, E21	Power for UCC2 Ethernet interface option 2 (2.5 V, 3.3 V)	LV <sub>DD</sub> 2	9
V <sub>DD</sub>	C36, D29, D35, E16, F9, F12, F15, F17, F18, F20, F21, F23, F25, F26, F29, F31, F32, F33, G6, J6, K32, M32, N6, P33, R6, R32, U32, V6, Y5, Y32, AB6, AB33, AD6, AF32, AK6, AL6, AM7, AM9, AM10, AM11, AM12, AM13, AM14, AM15, AM18, AM21, AM25, AM28, AM32, AN15, AN21, AN26, AU9, AU17	Power for core (1.2 V)	V <sub>DD</sub>	—
OV <sub>DD</sub>	A10, B9, B15, B32, C1, C12, C22, C29, D24, E3, E10, E27, G4, H35, J1, J35, K2, M4, N3, N34, R2, R37, T36, U2, U33, V4, V34, W3, Y35, Y37, AA1, AA36, AB2, AB34	PCI, 10/100 Ethernet, and other standard (3.3 V)	OV <sub>DD</sub>	—
MVREF1	AN20	I	DDR reference voltage	—
MVREF2	AU32	I	DDR reference voltage	—
SPARE1	B11	I/O	OV <sub>DD</sub>	8
SPARE3	AH32	—	GV <sub>DD</sub>	8
SPARE4	AU18	—	GV <sub>DD</sub>	7
SPARE5	AP1	—	GV <sub>DD</sub>	8

Table 72. CSB Frequency Options (continued)

CFG_CLKIN_DIV at Reset <sup>1</sup>	SPMF	csb_clk: Input Clock Ratio <sup>2</sup>	Input Clock Frequency (MHz) <sup>2</sup>			
			16.67	25	33.33	66.67
			csb_clk Frequency (MHz)			
Low	0110	6:1	100	150	200	
Low	0111	7:1	116	175	233	
Low	1000	8:1	133	200	266	
Low	1001	9:1	150	225	300	
Low	1010	10:1	166	250	333	
Low	1011	11:1	183	275		
Low	1100	12:1	200	300		
Low	1101	13:1	216	325		
Low	1110	14:1	233			
Low	1111	15:1	250			
Low	0000	16:1	266			
High	0010	2:1				133
High	0011	3:1				100
High	0100	4:1				133
High	0101	5:1				166
High	0110	6:1				200
High	0111	7:1				233
High	1000	8:1				
High	1001	9:1				
High	1010	10:1				
High	1011	11:1				
High	1100	12:1				
High	1101	13:1				
High	1110	14:1				
High	1111	15:1				
High	0000	16:1				

<sup>1</sup> CFG\_CLKIN\_DIV is only used for host mode; CLKIN must be tied low and CFG\_CLKIN\_DIV must be pulled down (low) in agent mode.

<sup>2</sup> CLKIN is the input clock in host mode; PCI\_CLK is the input clock in agent mode.

### Example 1. Sample Table Use

Index	SPMF	CORE PLL	CEPMF	CEPDF	Input Clock (MHz)	CSB Freq (MHz)	Core Freq (MHz)	QUICC Engine Freq (MHz)	400 (MHz)	533 (MHz)	667 (MHz)
A	1000	0000011	01001	0	33	266	400	300	∞	∞	∞
B	0100	0000100	00110	0	66	266	533	400	∞	∞	∞

- **Example A.** To configure the device with CSB clock rate of 266 MHz, core rate of 400 MHz, and QUICC Engine clock rate 300 MHz while the input clock rate is 33 MHz. Conf No. 's10' and 'c1' are selected from [Table 76](#). SPMF is 1000, CORPLL is 0000011, CEPMPF is 01001, and CEPDF is 0.
- **Example B.** To configure the device with CSBCSB clock rate of 266 MHz, core rate of 533 MHz and QUICC Engine clock rate 400 MHz while the input clock rate is 66 MHz. Conf No. 's5h' and 'c2h' are selected from [Table 76](#). SPMF is 0100, CORPLL is 0000100, CEPMPF is 00110, and CEPDF is 0.

## 22 Thermal

This section describes the thermal specifications of the MPC8360E/58E.

### 22.1 Thermal Characteristics

This table provides the package thermal characteristics for the 37.5 mm × 37.5 mm 740-TBGA package.

**Table 77. Package Thermal Characteristics for the TBGA Package**

Characteristic	Symbol	Value	Unit	Notes
Junction-to-ambient natural convection on single-layer board (1s)	$R_{\theta JA}$	15	°C/W	1, 2
Junction-to-ambient natural convection on four-layer board (2s2p)	$R_{\theta JA}$	11	°C/W	1, 3
Junction-to-ambient (@ 1 m/s) on single-layer board (1s)	$R_{\theta JMA}$	10	°C/W	1, 3
Junction-to-ambient (@ 1 m/s) on four-layer board (2s2p)	$R_{\theta JMA}$	8	°C/W	1, 3
Junction-to-ambient (@ 2 m/s) on single-layer board (1s)	$R_{\theta JMA}$	9	°C/W	1, 3
Junction-to-ambient (@ 2 m/s) on four-layer board (2s2p)	$R_{\theta JMA}$	7	°C/W	1, 3
Junction-to-board thermal	$R_{\theta JB}$	4.5	°C/W	4
Junction-to-case thermal	$R_{\theta JC}$	1.1	°C/W	5

$$T_J = T_B + (R_{\theta JB} \times P_D)$$

where:

$T_J$  = junction temperature (°C)

$T_B$  = board temperature at the package perimeter (°C)

$R_{\theta JA}$  = junction to board thermal resistance (°C/W) per JESD51-8

$P_D$  = power dissipation in the package (W)

When the heat loss from the package case to the air can be ignored, acceptable predictions of junction temperature can be made. The application board should be similar to the thermal test condition: the component is soldered to a board with internal planes.

## 22.2.3 Experimental Determination of Junction Temperature

To determine the junction temperature of the device in the application after prototypes are available, the Thermal Characterization Parameter ( $\Psi_{JT}$ ) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

$T_J$  = junction temperature (°C)

$T_T$  = thermocouple temperature on top of package (°C)

$\Psi_{JT}$  = junction-to-ambient thermal resistance (°C/W)

$P_D$  = power dissipation in the package (W)

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

## 22.2.4 Heat Sinks and Junction-to-Ambient Thermal Resistance

In some application environments, a heat sink is required to provide the necessary thermal management of the device. When a heat sink is used, the thermal resistance is expressed as the sum of a junction to case thermal resistance and a case to ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

$R_{\theta JA}$  = junction-to-ambient thermal resistance (°C/W)

$R_{\theta JC}$  = junction-to-case thermal resistance (°C/W)

$R_{\theta CA}$  = case-to-ambient thermal resistance (°C/W)

$R_{\theta JC}$  is device related and cannot be influenced by the user. The user controls the thermal environment to change the case-to-ambient thermal resistance,  $R_{\theta CA}$ . For instance, the user can change the size of the heat sink, the airflow around the device, the interface material, the mounting arrangement on printed-circuit board, or change the thermal dissipation on the printed-circuit board surrounding the device.

To illustrate the thermal performance of the devices with heat sinks, the thermal performance has been simulated with a few commercially available heat sinks. The heat sink choice is determined by the application environment (temperature, airflow, adjacent component power dissipation) and the physical space available. Because there is not a standard application environment, a standard heat sink is not required.

Millennium Electronics (MEI) Loroco Sites 671 East Brokaw Road San Jose, CA 95112 Internet: <a href="http://www.mei-millennium.com">www.mei-millennium.com</a>	408-436-8770
Tyco Electronics Chip Coolers™ P.O. Box 3668 Harrisburg, PA 17105-3668 Internet: <a href="http://www.chipcoolers.com">www.chipcoolers.com</a>	800-522-6752
Wakefield Engineering 33 Bridge St. Pelham, NH 03076 Internet: <a href="http://www.wakefield.com">www.wakefield.com</a>	603-635-5102

Interface material vendors include the following:

Chomerics, Inc. 77 Dragon Ct. Woburn, MA 01888-4014 Internet: <a href="http://www.chomerics.com">www.chomerics.com</a>	781-935-4850
Dow-Corning Corporation Dow-Corning Electronic Materials 2200 W. Salzburg Rd. Midland, MI 48686-0997 Internet: <a href="http://www.dowcorning.com">www.dowcorning.com</a>	800-248-2481
Shin-Etsu MicroSi, Inc. 10028 S. 51st St. Phoenix, AZ 85044 Internet: <a href="http://www.microsi.com">www.microsi.com</a>	888-642-7674
The Bergquist Company 18930 West 78th St. Chanhassen, MN 55317 Internet: <a href="http://www.bergquistcompany.com">www.bergquistcompany.com</a>	800-347-4572

## 22.3 Heat Sink Attachment

When attaching heat sinks to these devices, an interface material is required. The best method is to use thermal grease and a spring clip. The spring clip should connect to the printed-circuit board, either to the board itself, to hooks soldered to the board, or to a plastic stiffener. Avoid attachment forces which would lift the edge of the package or peel the package from the board. Such peeling forces reduce the solder joint lifetime of the package. Recommended maximum force on the top of the package is 10 lb force (4.5 kg force). If an adhesive attachment is planned, the adhesive should be intended for attachment to painted or plastic surfaces and its performance verified under the application requirements.